## NSN 5961-00-350-1369

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-350-1369 **Inclosure Material:** Glass and metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.187 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.187 inches **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 18.0 regulator voltage **Current Rating Per Characteristic:** 13.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded stud and 1 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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